**Vishay Semiconductors** 

High Performance Schottky Rectifier, 2 A



Cathode	Anode
0	0

SMA (DO-214AC)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 A			
V <sub>R</sub>	100 V			
V <sub>F</sub> at I <sub>F</sub>	0.72 V			
I <sub>RM</sub>	1 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	1.0 mJ			
Package	SMA (DO-214AC)			
Circuit configuration	Single			

www.vishay.com

#### **FEATURES**

- Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020. LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

The VS-20MQ100HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	Rectangular waveform	2	А	
V <sub>RRM</sub>		100	V	
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	120	А	
V <sub>F</sub>	2 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.72	V	
TJ	Range	-55 to +150	C°	

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-20MQ100HM3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	100	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current See fig. 4		50 % duty cycle at $T_L$ = 113 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		2.1	А
		50 % duty cycle at $T_L$ = 116 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		2	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	120	
non-repetitive surge current See fig. 6	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	30	A
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 0.5 \ A, \ L = 8 \ mH$		1.0	mJ
Repetitive avalanche current	I <sub>AR</sub>			0.5	А

Revision: 29-Jan-2025 Document Number: 94840 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000





## Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		2 A		0.91	V
		1.5 A	T <sub>J</sub> = 25 °C	0.85	
Maximum forward voltage drop	V <sub>EM</sub> <sup>(1)</sup>	1 A		0.78	
See fig. 1	V FM ()	2 A		0.72	
		1.5 A	T <sub>J</sub> = 125 °C	0.68	
		1 A		0.63	
Maximum reverse leakage current		$T_J = 25 \ ^{\circ}C$	$V_{\rm R} = \text{Rated } V_{\rm R}$ 0.1	0.1	mA
See fig. 2	I <sub>RM</sub>	T <sub>J</sub> = 125 °C		1	
Threshold voltage	V <sub>F(TO)</sub>	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.52	V
Forward slope resistance	r <sub>t</sub>			mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}, T_J = 25 \text{ °C}, \text{ test signal} = 1 \text{ MHz}$ 3		38	pF
Typical series inductance	LS	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µ		V/µs	

#### Note

<sup>(1)</sup> Pulse width = 300  $\mu$ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +150	°C
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W
Approvimeto weight			0.07	g
Approximate weight			0.002	oz.
Marking device		Case style SMA (DO-214AC) (similar D-64)	2	J

#### Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ 



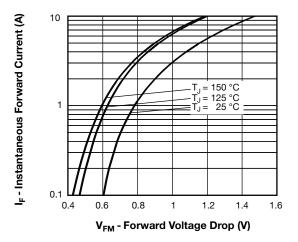


Fig. 1 - Maximum Forward Voltage Drop Characteristics

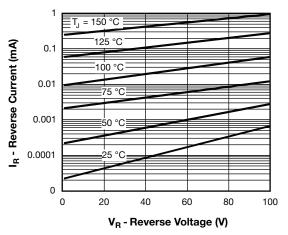


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

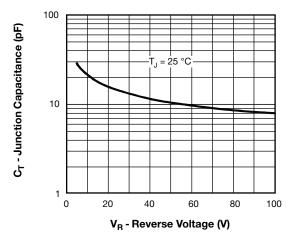


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

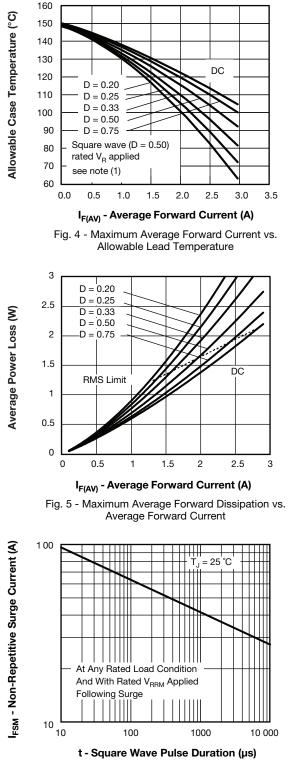


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

**Vishay Semiconductors** 

Revision: 29-Jan-2025

3

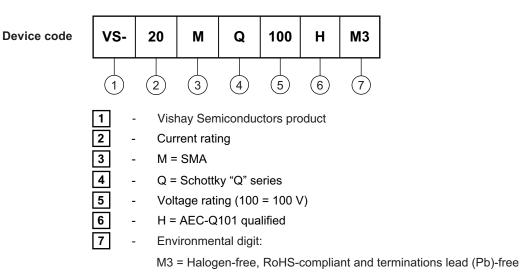
Document Number: 94840

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

### **Vishay Semiconductors**



#### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)					
PREFERRED P/N PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-20MQ100HM3/5AT	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95400		
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		
SPICE model	www.vishay.com/doc?97121		



# **Outline Dimensions**

## **Vishay Semiconductors**

SMA

### **DIMENSIONS** in inches (millimeters)

DO-214AC (SMA)





Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1